TOSHIBA SCHOTTKY BARRIER RECTIFIER STACK SCHOTTKY BARRIER TYPE

10FWJ2CZ47M

LOW FORWARD VOLTAGE SCHOTTKY BARRIER DIODE

SWITCHING TYPE POWER SUPPLY APPLICATION CONVERTER & CHOPPER APPLICATION

• Peak Forward Voltage : V_{FM}≤0.47V

• Repetitive Peak Reverse Voltage : V_{RRM}=30V

• Average Output Rectified Current: IO=10A

• Low Switching Losses and Output Noise.

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	30	V	
Average Output Rectified Current	IO	10	A	
Peak One Cycle Surge Forward	Incar	100 (50Hz)	A	
Current (Sine Wave)	IFSM	110 (60Hz)		
Junction Temperature	T_j	-40~125	°C	
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~150	°C	
Screw Torque	_	0.6	N∙m	

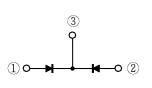
Weight: 2.0g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

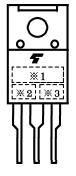
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage (Note 1)	$v_{ m FM}$	I _{FM} =5A	_	_	0.47	v
Repetitive Peak Reverse Current (Note 1)	I_{RRM}	V_{RRM} =30V	_	_	3.5	mA
Junction Capacitance (Note 1)	Cj	$V_R = 10V, f = 1.0MHz$	_	290	_	pF
Thermal Resistance	R _{th (j-c)}	DC Total, Junction to Case	_	_	3.0	°C/W

(Note 1) A value of one cell.

POLARITY



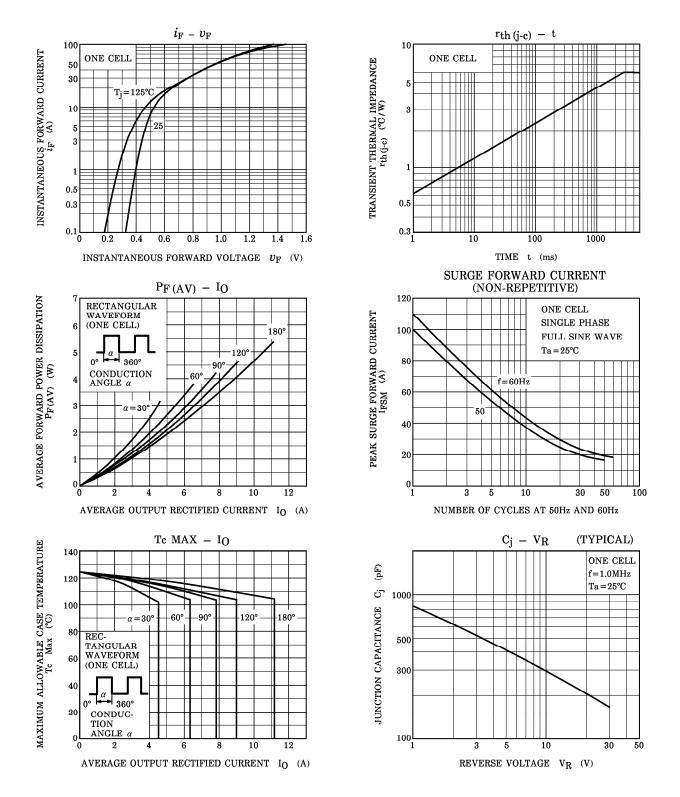
MARKING



*1	MARK	10FWJ2CZ	TYPE	10FWJ2CZ47M
*2	M			
*3		Month (Starti		lphabet A) he Christian Era)

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